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June 2016

FSA2276 — DPDT (0.5 Ω) HiFi Audio Switch w/ Negative Swing

Features

- V_{DD} Operating Range: 1.65 to 5.5 V
- External Capacitor Connection for Pop and Click Noise Suppression
- Power-Off Protection on Common Ports
- R_{ON} = 0.5 Ω (Typ.) at 1.8 V
- THD+N = -115 dB; 2 V_{RMS}, 20 kΩ Load; f = 1 kHz
- X_{TALK} = -122 dB at 1 V_{RMS}, 50 Ω Load; f = 1 kHz
- Off Isolation = -115 dB at 1 V_{RMS}, 50 Ω Load; f = 1 kHz
- 12-Lead UMLP 1.8 mm x 1.8 mm

Applications

- Mobile Phone, Tablet, Notebook PC, Media Player
- Docking Station, TV, Set-Top Box, LCD Monitor

Description

The FSA2276 is a high-performance, Double-Pole Double-Throw (DPDT) analog switch with negative swing audio capability. The FSA2276 features ultra-low audio R_{ON} of $0.5\,\Omega$ (typical) at $1.8\,V\,V_{DD}$. The FSA2276 operates over a V_{DD} range of $1.65\,V$ to $5.5\,V$, is fabricated with sub-micron CMOS technology to achieve fast switching speeds, and is designed for break-before-make operation. To minimize pop and click during operation, the turn on ramp time is selectable using an external capacitor (C_EXT).

The FSA2276 features THD+N specifications that target a Hi-Fidelity audio quality into both 32 Ω headphones and line out type loads (>600 Ω).



Figure 1. Application Block Diagram

Ordering Inform	nation		
Part Number	Top Mark	Package Description	
FSA2276UMX	EN	12-Lead, UMLP, Quad, JEDEC MO252, 1.8 mm x 1.8 mm	



Figure 2. Pin Assignment (Top Through View)

Pin Descriptions



Figure 3. Pin Assignment (Bottom View)

Pin	Name	Description		
1	VDD	Power Supply (1.65 to 5.5 V)		
2	C_EXT	Slow Turn On External Capacitor		
3	GND	iround		
4	L _{SPKR}	udio L _{SPPKR} Common I/O Port		
5	R _{SPKR}	Audio R _{SPPKR} Common I/O Port		
6	SEL	Select Pin		
7	MUTE	Mute Enable - Active High		
8	GND	Ground		
9	R2	Audio – Right Channel Source2 I/O Port		
10	R1	Audio – Right Channel Source1 I/O Port		
11	L2	Audio – Left Channel Source2 I/O Port		
12	L1	Audio – Left Channel Source1 I/O Port		

Truth Table

Mute	SEL	Function	Resistor Terminations
0	0	$L1 = L_{SPKR}; R1 = R_{SPKR}$	R _{SHUNT(s)} connect to L2/R2
0	1	$L2 = L_{SPKR}; R2 = R_{SPKR}$	R _{SHUNT(s)} connect to L1/R1
1	0	L1 ≠ L _{SPKR} ; L2 ≠ L _{SPKR} ; R1 ≠ R _{SPKR} ; R2 ≠ R _{SPKR} (All Paths Hi-Z)	R _{SHUNT(s)} OPEN
1	1	L1 ≠ L _{SPKR} ; L2 ≠ L _{SPKR} ; R1 ≠ R _{SPKR} ; R2 ≠ R _{SPKR} (All Paths Hi-Z)	R _{SHUNT(s)} OPEN

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter			Max.	Unit
V _{DD}	Supply/Control Voltage		-0.3	6.0	V
V _{CNTRL}	Control Input Voltage	SEL, MUTE	-0.3	6.0	V
V _{SW}	DC Switch I/O Voltage	L1, L2, R1, R2, L _{SPKR} , R _{SPKR}		3.5	V
l _{IK}	ESD Input Diode Current			-50	mA
Isw	Switch I/O Current			700	mA
	Human Body Model, ANSI/ESDA/ JEDEC JS-001-2012	All Pins	5		
ESD	Charged Device Model, JEDEC: JESD22-C101		2		kV
		Contact	8		
	Air Gap		15		
T _A	Absolute Maximum Operating Temperature		-40	+85	°C
T _{STG}	Storage Temperature		-65	+150	°C

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Min.	Тур.	Max.	Unit
V _{DD}	Supply Voltage		1.65	1.80	5.50	V
V _{SW}	DC Switch I/O Voltage	L1, L2, R1, R2, L _{SPKR} , R _{SPKR}	-3.0		3.0	V
VCNTRL	Control Input Voltage SEL, MUTE		0		V _{DD}	V
Isw	DC Switch I/O Current			100		mA
T _A	Ambient Operating Temperatu	re la	-40	25	+85	°C

FSA2276 — DPDT (0.5 Ω) HiFi Audio Switch w/ Negative Swing

	DC	Characteristics
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 V_{DD} = 1.65 V to 5.5 V, V_{DD} (Typ.) = 1.8 V, T_A = -40°C to 85°C, and T_A (Typ.) = 25°C, unless otherwise specified.⁽¹⁾

Symbol	Parameter	Condition	V _{DD} (V)	T _A =-40°C to +85°C			Unit
				Min.	Тур.	Max.	
VIH	VCNTRL Pin Input High Voltage (SEL, MUTE)	C_EXT = FLOAT		1.17		VDD	V
VIL	VCNTRL Pin Input Low Voltage (SEL, MUTE)	C_EXT = FLOAT C_EXT = FLOAT		0		0.5	V
I _{ON}	Switch-to-Gnd ON Leakage Current	I-to-Gnd ON Leakage $L1, R1, L2, R2 = -3 V \text{ to } 3 V, L_{SPKR}, R_{SPKR} = Float (I_{SW} = 0 mA) MUTE=LOW, SEL=0 or VDD C_EXT = FLOAT. Figure 6 1$		-1.0	0.1	1.0	μA
I _{NO_MUTE}	$ \begin{array}{l} \mbox{Switch-to-Gnd OFF} \\ \mbox{Leakage Current (when} \\ \mbox{Muted}) \end{array} \begin{array}{l} \mbox{L1, R1, L2, R2 = -3 V to 3 V, L_{SPKR},} \\ \mbox{R}_{SPKR} = \mbox{Float (I}_{SW} = 0 \mbox{ mA}) \\ \mbox{MUTE = HIGH, SEL = 0 or VDD} \\ \mbox{C EXT = FLOAT, Figure 5} \end{array} \end{array} . $		1.65 to 5.5	-1.0	0.1	1.0	μA
I _{OFF}	Input Leakage Current ⁽²⁾	L1, R1, L2, R2 = -3 V to 3 V, L _{SPKR} , R _{SPKR} = Float (I _{SW} = 0 mA) MUTE = LOW, SEL = 0 or VDD, C_EXT = FLOAT	0	-1.0	0.1	1.0	μA
l _{in}	Control Input Leakage Current ⁽³⁾ (SEL, MUTE)	L1, R1, L2, R2 = -3 V to 3 V, L_{SPKR} , R _{SPKR} = Float (I _{SW} = 0 mA), C_EXT = FLOAT	1.65 to 5.5	-0.5	0.1	0.5	μΑ
IDD	VDD Supply Current	MUTE = LOW, SEL = 0 or VDD, C_EXT = FLOAT	5.5		16	30	μA
I _{DDZ}	VDD Hi-Z Supply Current	MUTE = HIGH, SEL = 0 or VDD, C_EXT = FLOAT	5.5			1	μA
I _{DDT}	Increase in IDD per Control Voltage	MUTE = LOW, SEL = 0 or 1.8 V SEL = LOW, MUTE = 0 or 1.8 V C_EXT = FLOAT	5.5			1	μA
R _{ON}	Switch On Resistance	ISW = 100 mA, V _{SW} = -3 V to 3 V C_EXT = FLOAT, Figure 4	1.65 to 5.5		0.5	1.0	Ω
ΔR _{ON}	On Resistance Matching, Channel to Channel	ISW = 100 mA, V _{SW} = -3 V to 3 V C_EXT = FLOAT	1.65 to 5.5		30		mΩ
R _{FLAT}	On Resistance Flatness	ISW = 100 mA, V_{SW} = -3 V to 3 V C_EXT = FLOAT	1.65 to 5.5		1		mΩ
R _{SHUNT}	Click and Pop Resistance (L1, L2, R1, R2, L _{SPKR} , R _{SPKR})	VLX_RX = 3.0 V, MUTE = 0, SEL = 0 or VDD, C_EXT = FLOAT		6	10	14	kΩ

Notes:

1. Limits over the recommended temperature operating range ($T_A = -40^{\circ}C$ to $+85^{\circ}C$) are correlated by statistical quality.

2. Only valid for $V_{SW} > 0 V$.

3. $V_{MUTE} \le V_{DD} + 0.3$ otherwise additional input leakage current may flow.

Symbol	Deremeter	Condition			T _A =- 40°C to +85°C			11014
Symbol	Farameter	Condition	V _{DD} (V)	Min.	Тур.	Max.	Unit	
	Enable Time	L1 = R1 = L2 = R2 = 1.5 V,	C_EXT = Float	1.8, 3.3		0.5		
t _{MUTE_ON}	(MUTE to	L _{SPKR} , R _{SPKR} = 50 Ω to GND SEL= 0 or V _{DD} : See Figure 7	C_EXT = 0.1 μF	1.8		60		ms
	Output)	and Figure 8	C_EXT = 0.1 μF	3.3		100		
	Disable Time	$\begin{array}{l} L1 = R1 = L2 = R2 = 1.5 \text{ V}, \\ L_{SPKR} \text{ , } R_{SPKR} = 50 \ \Omega \text{ to GND}, \end{array}$	C_EXT = Float	1833		35		us
CIN_MOTE	Output)	SEL = 0 or V _{DD} ; See Figure 7 and Figure 8	C_EXT = 0.1 μF	110, 010		35		μο
		L1 (L2) = R1 (R2) = 1.5 V , L2 (L1) = R2 (R1) = 0 V	C_EXT = Float	1.8, 3.3		0.5		
t _{ON_SEL}	Turn On Time (SEL to Output)	$L_{SPKR}, R_{SPKR} = 50 \Omega \text{ to GND},$	C_EXT = 0.1 μF	1.8		50		ms
	1	See Figure 7 and Figure 8	C_EXT = 0.1 μF	3.3		100		
toff sti	Turn On Time	L1 (L2) = R1 (R2) = 1.5 V, L2 (L1) = R2 (R1) = 0 V L _{SPKB} , R _{SPKB} = 50 Ω to GND,	C_EXT = Float	1.8. 3.3	20		цs	
-011_000	(SEL to Output)	SEL= 0 or V_{DD} ; MUTE = 0 See Figure 7 and Figure 8	$\begin{array}{c} 0 \text{ or } V_{DD}; \text{ MUTE} = 0 \\ \hline \text{Figure 7 and Figure 8} \end{array} C_EXT = 0.1 \ \mu\text{F}$			20		P**
t _{BBM}	Break Before Make Time (SEL to Output)	L1 (L2) = R1 (R2) = 1.5 V, L _{SF} R _{SPKR} = 50 Ω to GND,SEL = 0 C_EXT = FLOAT, MUTE = 0 See Figure 7 and Figure 9	∾ĸĸ,) or V _{DD} ; V;	1.8, 3.3		500		μs
0.55	O ⁽⁴⁾ (4)	$ f = 1 \text{ kHz}, \text{R}_{\text{L}} = 50 \Omega, \text{C}_{\text{L}} = 0 \text{ pF}, \\ \text{MUTE} = 0 \text{V}_{\text{SW}} = 1 \text{V}_{\text{RMS}} \text{ Figure 11} $		1833		-115		dB
OIRR	Christiation	$ f = 1 \ MHz, \ R_L = 50 \ \Omega, \ C_L = 0 \ p \\ MUTE = 0 \ V_{SW} = 1 \ V_{RMS} \ Figure $	oF, re 11	1.0, 3.5		-92		UD
Olean	Off Isolation-	$ f = 1 \text{ kHz}, \text{R}_{\text{L}} = 50 \Omega, \text{C}_{\text{L}} = 0 \text{ pl} \\ \text{MUTE} = \text{V}_{\text{DD}} \text{; } \text{V}_{\text{SW}} = 1 \text{V}_{\text{RMS}} \text{F} $	F, igure 11	1833	-113		dB	
	Muted ⁽⁴⁾	f = 1 MHz, R_L = 50 Ω , C_L = 0 pF, MUTE = V _{DD} ; V_{SW} = 1 V_{RMS} Figure 11		1.0, 3.3				-95
X _{TALK}	Cross Talk (Adjacent) ⁽⁴⁾	f = 1 kHz, R _L = 50 Ω, V _{SW} = 1 Figure 12	V _{RMS}	1.8, 3.3	1.	-122		dB
BW	-3 dB Bandwidth ⁽⁴⁾	$R_L = 50 \ \Omega$ Figure 10		1.8, 3.3		380		MHz
DODD	Power Supply	$V_{PSRR} = V_{DD} + 100 \text{ mV}_{RMS}$ R _L = 20 k Ω or 32 Ω (at L _{SPKR} ,	R _L = 32 Ω	1.8, 3.3		-119		
PSRR	Rejection Ratio ⁽⁴⁾	R_{SPKR} , MUTE = 0 or V _{DD} , f = 1 kHz, V _{SW} = GND or Floa	t) $R_L = 20 k\Omega$			-105		aB
		R_L = 20 k Ω , f = 1 kHz,				0.00018		%
		$V_{SW} = 2 V_{RMS}$, With A-weighte	ed, Figure 15			-115		dB
тно∓м	Total Harmonic	$R_L=600 \Omega$, f = 1 kHz, $V_{SW} = 2$	V _{RMS}			0.00018		%
	Noise ⁽⁴⁾	With A-weighted, Figure 15				-115		dB
		$R_L = 32 \ \Omega, f = 1 \ kHz, V_{SW} = 1$	V _{RMS} ,			0.00018		%
		With A-weighted, Figure 15				-115		dB

AC Characteristics

Note:

4. Guaranteed by characterization. Not production tested.

T _A =- 4	Unit		
Min.	Тур.	Max.	•
	22		pF
	25		pF
	14		pF
	14		pF
	3		рЕ
	6		р
re corre	elated by	statistica	I

FSA2276 — DPDT (0.5 Ω) HiFi Audio Switch w/ Negative Swing

Unless otherwise stated, $V_{DD} = 1.65$ V to 5.5 V, V_{DD} (Typ.) = 1.8 V, $T_A = -40^{\circ}$ C to 85°C, and T_A (Typ.) = 25°C.⁽⁵⁾

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	LIOKOMOTOK						
Symbol	Farameter	Condition		V _{DD} (V)	Min.	Тур.	N
C _{ON}	On Capacitance (Common Port) ⁽⁶⁾	$f = 1 \text{ MHz}, 100 \text{ mV}_{PK-PK}, 100 \text{ mV}$ DC bias MUTE = 0 V Figure 14		1.8, 3.3		22	
C_{OFF1}	Off Capacitance (Common Port) ⁽⁶⁾	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias MUTE = V_{DD} Figure 13		1.8, 3.3		25	
C_{OFF2}	Off Capacitance (Non-Common Ports) ⁽⁶⁾	f = 1 MHz, 100 mV _{PK-PK} , 100 mV DC bias MUTE = 0 V Figure 13		1.8, 3.3		14	
$C_{\text{OFF}_\text{MUTE}}$	Off Capacitance - MUTED (Non-Common Ports) ⁽⁶⁾	f = 1 MHz, 100 mV _{PK-PK} , 10 DC bias, MUTE = V_{DD}	0 mV	1.8, 3.3		14	
CONTRI	Control Input Pin	f = 1 MHz, 100 mV _{PP} ,	SEL	0		3	
CONTRL	(MUTE, SEL) ⁽⁶⁾	100 mV DC bias	MUTE	0		6	
NI - I							

Notes:

5. Limits over the recommended temperature operating range (T_A =-40°C to +85°C) are correlated by statistical quality control methods.

6. Guaranteed by characterization. Not production tested.







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